NSN 5961-01-625-4409

Transistor - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-625-4409
Inclosure Material:
Glass
Overall Length:
Between 0.106 inches and 0.122 inches
Terminal Length:
Between 0.024 inches and 0.025 inches
Overall Height:
Between 0.039 inches and 0.051 inches
Overall Width:
Between 0.099 inches and 0.118 inches
Function For Which Designed:
Switching
Mounting Facility Quantity:
3
Internal Configuration:
Junction contact-darlington connected
Internal Junction Configuration:
Npn
Mounting Method:
Press fit
Semiconductor Material:
Silicon
Voltage Rating In Volts Per Characteristic:
50.0 collector to base voltage, dc and 50.0 collector to emitter voltage, dc with specified circuit between base and emitter and 50.0
breakdown voltage, collector-to-base, emitter open and 50.0 breakdown voltage, collector-to-emitter, with specified resistance between
base and emitter and 0.25 collector to emitter voltage, dc with base short-circuited to emitter and 0.2 on-state voltage, dc and 4.90
off-state voltage, dc
Current Rating Per Characteristic:
100.0 nanoamperes collector cutoff current, dc, base open and 500.0 nanoamperes collector cutoff current, dc, emitter open and 0.5
milliamperes collector cutoff current, dc, with base short-circuited to emitter and 100.0 milliamperes collector current, dc
Power Rating Per Characteristic:
230.0 milliwatts total device dissipation
Maximum Operating Tempurature Per Measurement Point:
150.0 degrees celsius ambient air
Special Features:
3000 units to a reel from on semiconductor, smaller quantities may be ordered through mouser electronics cage 1jn02 and p/n
863-mun2211t1g, rohs compliant -lead free
Terminal Type And Quantity:

Demilitarization:

3 tab, solder lug

Unit Of Measure:

Shelf Life:

N/a